NCE Automotive N-Channel Super Trench Power MOSFET

Description

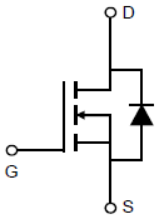
The NCEAP0135AK uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g. This device is ideal for high-frequency switching and synchronous rectification.

General Features

- V_{DS} =100V,I_D =35A
  $R_{DS(ON)}$=18mΩ (typical) @ V_{GS}=10V
  $R_{DS(ON)}$=22mΩ (typical) @ V_{GS}=4.5V
- Excellent gate charge x $R_{DS(on)}$ product(FOM)
- Very low on-resistance $R_{DS(on)}$
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- **AEC-Q101 qualified**

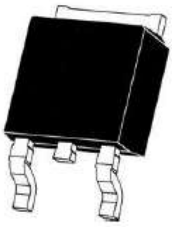
Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Schematic Diagram

Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP0135AK	NCEAP0135AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I_D	35	A
Drain Current-Continuous(T_C=100℃)	I_D (100℃)	24.7	A
Pulsed Drain Current	I_{DM}	140	A
Maximum Power Dissipation	P_D	70	W
Derating factor		0.47	W/℃
Single pulse avalanche energy (Note 5)	E_{AS}	200	mJ
Operating Junction and Storage Temperature Range	T_J,T_{STG}	-55 To 175	℃

Thermal Characteristic

Thermal Resistance,Junction-to-Case(Note 2)	$R_{\theta JC}$	2.14	℃/W

Electrical Characteristics (T_C=25℃unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V I_D=250μA	100		-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=100V,V_{GS}=0V	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=250μA	1.2	2.0	2.8	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=20A	-	18	23	mΩ
		V_{GS}=4.5V, I_D=20A	-	22	27	mΩ
Forward Transconductance	g_{FS}	V_{DS}=5V,I_D=20A	-	35	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C_{lss}	V_{DS}=50V,V_{GS}=0V, F=1.0MHz	-	1600	-	PF
Output Capacitance	C_{oss}		-	139	-	PF
Reverse Transfer Capacitance	C_{rss}		-	11	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	V_{DD}=50V,I_D=20A V_{GS}=10V,R_G=1.6Ω	-	6	-	nS
Turn-on Rise Time	t_r		-	2	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	18	-	nS
Turn-Off Fall Time	t_f		-	2	-	nS
Total Gate Charge	Q_g	V_{DS}=50V,I_D=20A, V_{GS}=10V	-	26	-	nC
Gate-Source Charge	Q_{gs}		-	7.4		nC
Gate-Drain Charge	Q_{gd}		-	3.8		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V_{GS}=0V,I_S=35A	-		1.2	V
Diode Forward Current (Note 2)	I_S		-	-	35	A
Reverse Recovery Time	t_{rr}	T_J = 25°C, I_F = 20A di/dt = 500A/μs(Note3)	-		26	nS
Reverse Recovery Charge	Qrr		-		98	nC

Notes:

1. The value of $R_{\theta JA}$ is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25° C.
2. Guaranteed by design, not subject to production
3. EAS condition : Tj=25℃,V_{DD}=50V,V_G=10V,L=0.5mH,Rg=25Ω

Typical Electrical and Thermal Characteristics

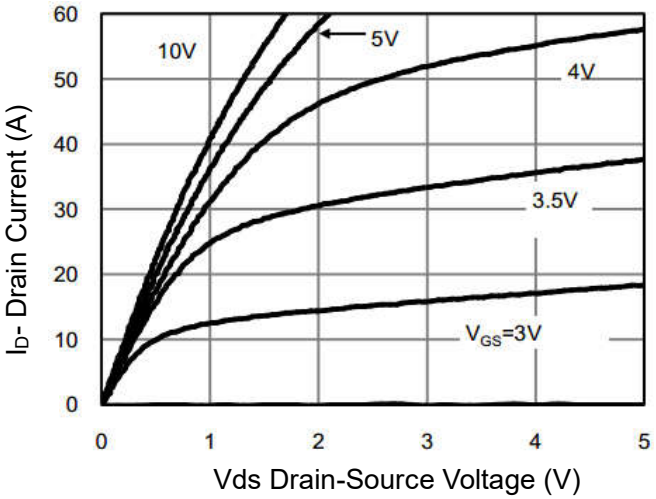


Figure 1 Output Characteristics

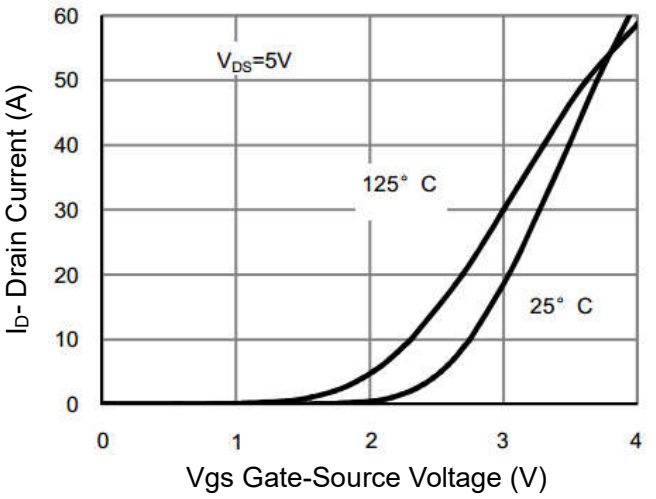


Figure 2 Transfer Characteristics

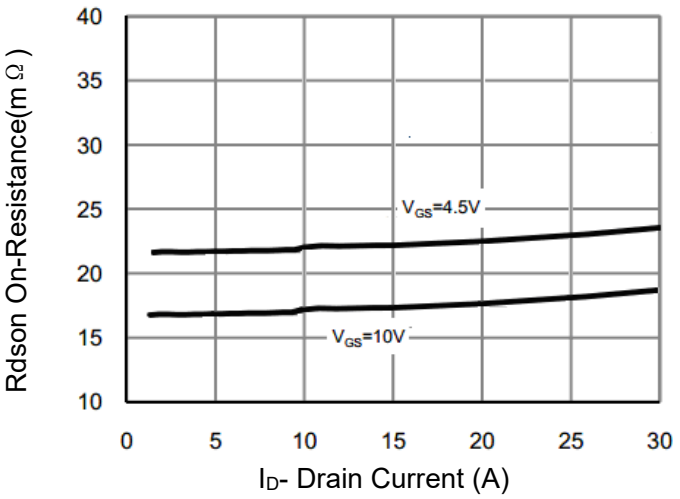


Figure 3 Rdson- Drain Current

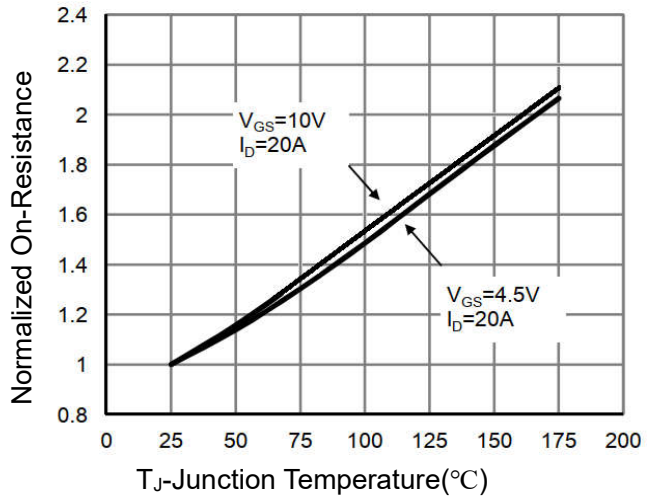


Figure 4 Rdson-Junction Temperature

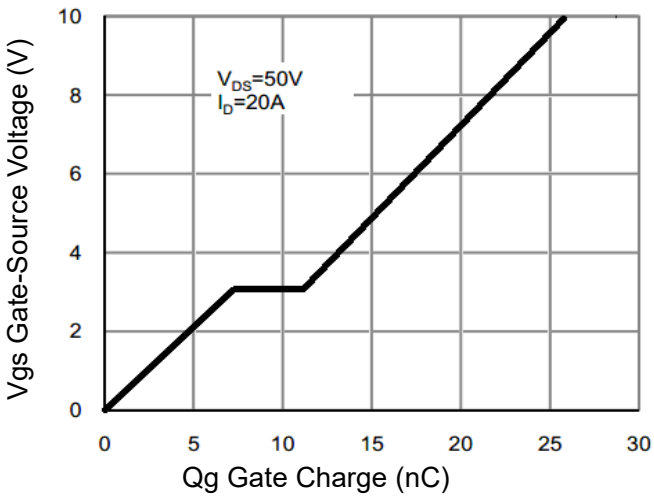


Figure 5 Gate Charge

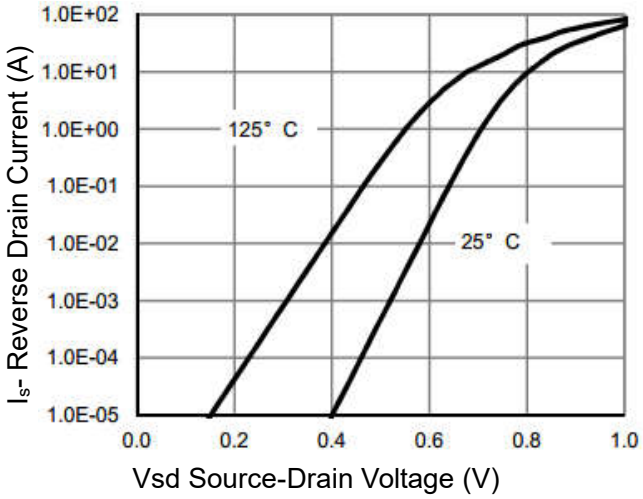


Figure 6 Source- Drain Diode Forward

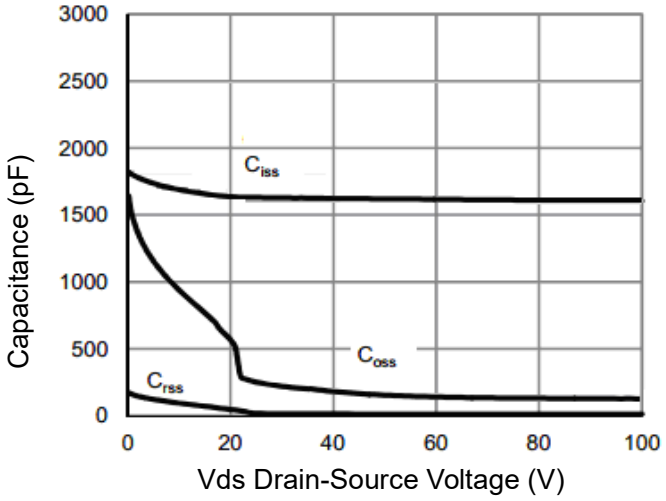


Figure 7 Capacitance vs Vds

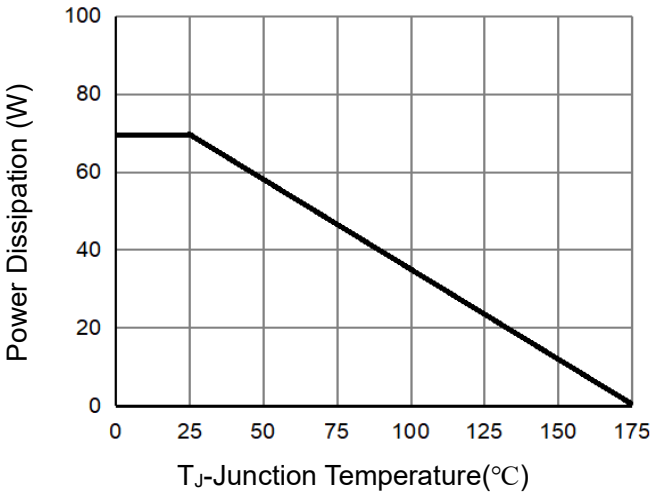


Figure 9 Power De-rating

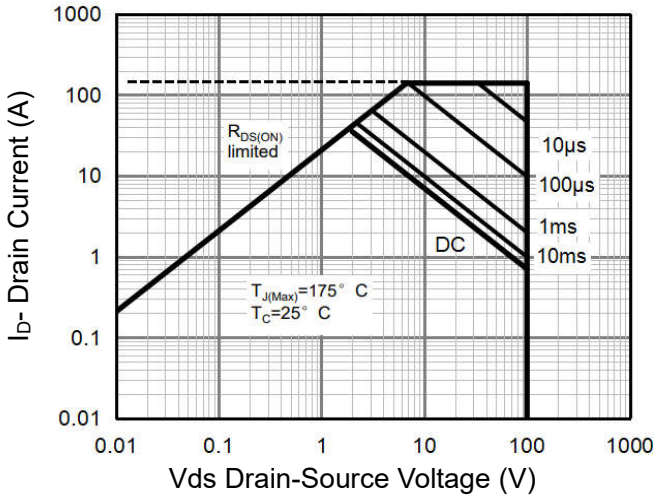


Figure 8 Safe Operation Area

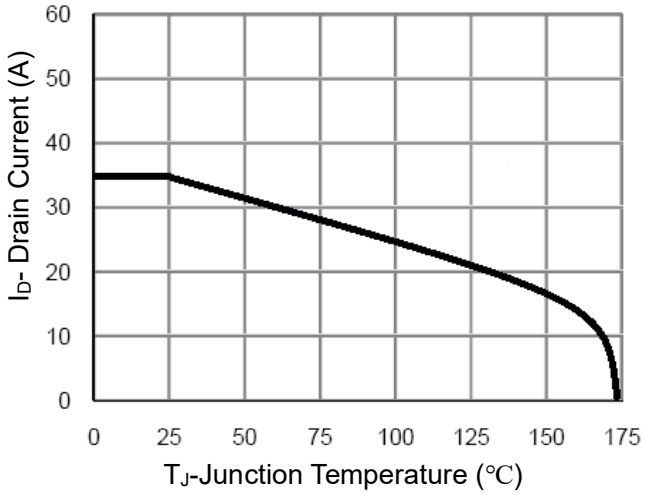


Figure 10 Current De-rating

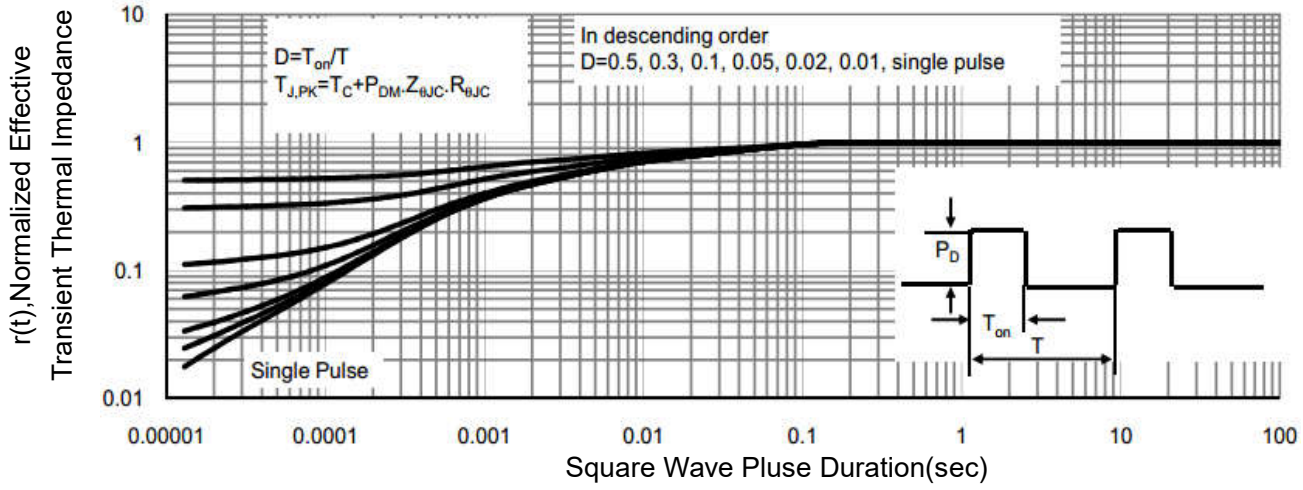
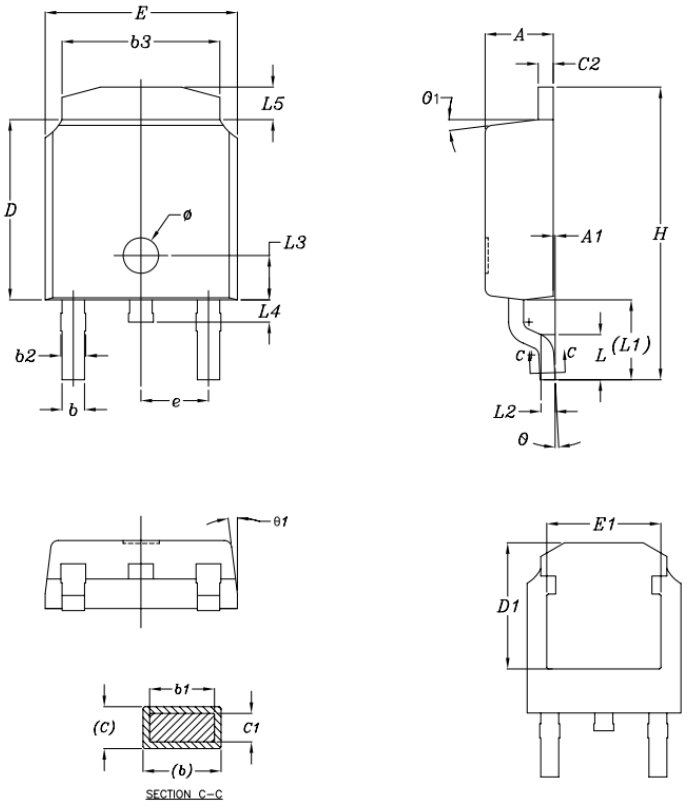


Figure 11 Normalized Maximum Transient Thermal Impedance

TO-252-2L Package Information



ITEM	DIMENSIONS			
	MILLMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.18	2.39	0.086	0.094
A1	——	0.13	——	0.005
b	0.70	0.89	0.028	0.035
b1	0.70	0.86	0.028	0.034
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
c	0.46	0.61	0.018	0.024
c1	0.41	0.56	0.016	0.022
c2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	5.21	——	0.205	——
E	6.35	6.73	0.250	0.265
E1	4.32	——	0.170	——
e	2.29 BSC		0.090 BSC	
H	9.40	10.41	0.370	0.410
L	1.40	1.78	0.055	0.070
L1	2.60	2.90	0.102	0.114
L2	0.51 BSC		0.020 BSC	
③ L3	1.65	1.95	0.065	0.077
L4	0.60	0.90	0.024	0.035
③ L5	0.89	1.27	0.035	0.050
θ	1°	5°	1°	5°
θ1	7° REF		7° REF	
ø	1.20 REF		1.20 REF	

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